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ON Semiconductor®



FCMT099N65S3 N-Channel SuperFET[®] III MOSFET 650 V, 30 A, 99 mΩ

Features

- 700 V @ T_J = 150 °C
- Typ. R_{DS(on)} = 87 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 56 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = TBD pF)
- 100% Avalanche Tested
- RoHS Compliant

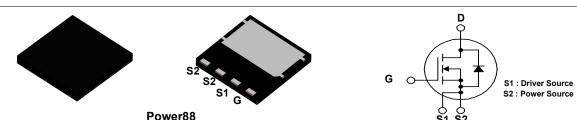
Applications

- Server and Telecom Power Supplies
- Solar Inverters
- Adaptors

Description

SuperFET[®] III MOSFET is ON Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET III MOSFET is very suitable for the switching power applications such as server/telecom power, adaptor and solar inverter applications.

The Power88 package is an ultra-slim surface-mount package (1 mm high) with a low profile and small footprint (8x8 mm²). SuperFET III MOSFET in a Power88 package offers excellent switching performance due to lower parasitic source inductance and separated power and drive sources. Power88 offers Moisture Sensitivity Level 1 (MSL 1).



Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

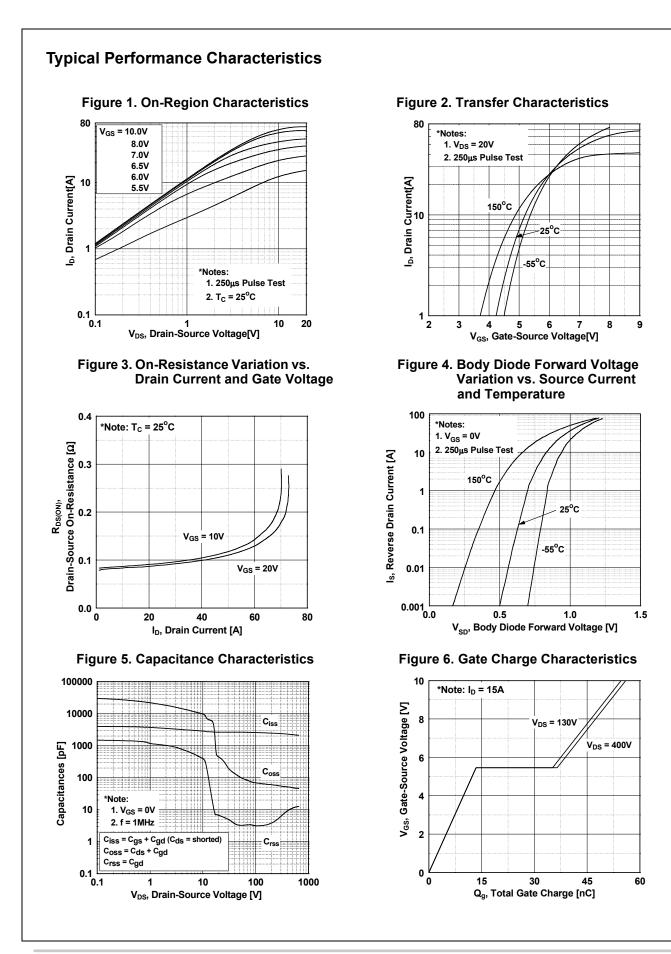
Symbol		FCMT099N65S3	Unit V		
V _{DSS}	Drain to Source Voltage	650			
V _{GSS}	Cata ta Source Valtage	- DC	±30	V	
	Gate to Source Voltage	- AC (f > 1 Hz)	±30	V	
ID	Drain Current	- Continuous (T _C = 25 ^o C)	30	A	
	Drain Current	- Continuous (T _C = 100 ^o C)	19		
I _{DM}	Drain Current	- Pulsed (Note 1)	75	Α	
E _{AS}	Single Pulsed Avalanche Energy	145	mJ		
I _{AS}	Avalanche Current	4.4	Α		
E _{AR}	Repetitive Avalanche Energy (Note 1)		2.27	mJ	
dv/dt	MOSFET dv/dt	100	V/ns		
	Peak Diode Recovery dv/dt	20			
P _D	Devuer Dissingtion	(T _C = 25 ^o C)	227	W	
	Power Dissipation	- Derate Above 25°C	1.82	W/ºC	
T _J , T _{STG}	Operating and Storage Temperatu	-55 to +150	°C		
TL	Maximum Lead Temperature for S	300	°C		

Thermal Characteristics

Symbol	Parameter	FCMT099N65S3	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.55	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	45	°C/VV

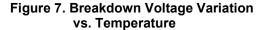
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FCMT099N65S3 — N-Char
nnel SuperFET [®] I
III MOSFET

	Number	Top Mark	Package	Reel Size	Таре	Width	Qua	ntity
FCMT099N65S3 FCMT099N65S3		Power88 13"		13.3 mm		3000		
Electrica	I Characte	eristics T _C = 25°C unles	ss otherwise noted	1.				
Symbol		Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristics			L			1	1
	Drain to Source Breakdown Voltage		$V_{00} = 0 V l_{D} =$	1 mA T, = 25°C	650	_	_	V
BV _{DSS}			$V_{GS} = 0 V, I_D = 1 mA, T_J = 25^{\circ}C$ $V_{GS} = 0 V, I_D = 1 mA, T_J = 150^{\circ}C$		700	-	-	V
ΔBV _{DSS} / ΔΤ.Ι	Breakdown Voltage Temperature Coefficient		$I_D = 1$ mA, Referenced to 25°C		-	0.68	-	V/°C
	Zero Gate Voltage Drain Current		V _{DS} = 650 V, V _{GS} = 0 V		-	-	10	
IDSS			V _{DS} = 520 V, T	_C = 125°C	-	2.77	-	μA
I _{GSS}	Gate to Body	Leakage Current	V_{GS} = ±30 V, V	_{DS} = 0 V	-	-	±100	nA
On Charac	teristics							
V _{GS(th)}	Gate Thresho	ld Voltage	$V_{GS} = V_{DS}$, $I_D = 3 \text{ mA}$		2.5	-	4.5	V
R _{DS(on)}	Static Drain to	Source On Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 15 \text{ A}$		-	87	99	mΩ
9 FS	Forward Transconductance $V_{DS} = 20 \text{ V}, I_D = 15 \text{ A}$				-	17	-	S
Dynamic C	haracteristi	cs						
C _{iss}	Input Capacita		V _{DS} = 400 V, V _{GS} = 0 V,		-	2270	-	pF
C _{oss}	Output Capacitance		f = 1 MHz		-	50	-	pF
C _{oss(eff.)}	Effective Output Capacitance		V _{DS} = 0 V to 40	-	500	-	pF	
C _{oss(er.)}	Energy Relate	inergy Related Output Capacitance $V_{DS} = 0 V$ to 400 V, $V_{GS} = 0 V$		-	74	-	pF	
Q _{g(tot)}	Total Gate Cha	arge at 10V	V _{DS} = 400 V, I _E	₀ = 15 A,	-	56	-	nC
Q _{gs}	Gate to Sourc	e Gate Charge	V _{GS} = 10 V (Note 4)		-	13	-	nC
Q _{gd}		"Miller" Charge			-	23	-	nC
ESR	Equivalent Se	Equivalent Series Resistance f = 1 MHz				0.5	-	Ω
Switching	Characteris	tics						
t _{d(on)}	Turn-On Delay	/ Time	V _{DD} = 400 V, I _D = 15 A,		-	22	-	ns
t _r	Turn-On Rise	Time			-	20	-	ns
t _{d(off)}	Turn-Off Delay	/ Time	V _{GS} = 10 V, R _g	= 4.7 Ω	-	58	-	ns
t _f	Turn-Off Fall T	ïme	(Note 4)		-	5	-	ns
Source-Dr	ain Diode Cl	naracteristics						
I _S	Maximum Continuous Source to Drain Diode Forward Current				-	-	30	Α
	Maximum Pulsed Source to Drain Diode Forward Current			-	-	75	Α	
ISM	Drain to Sourc	e Diode Forward Voltage	V _{GS} = 0 V, I _{SD} = 15 A		-	-	1.2	V
I _{SM} V _{SD}		vony Timo	$V_{GS} = 0 V, I_{SD} = 15 A,$		-	352	-	ns
	Reverse Reco		dI _F /dt = 100 A/μs					



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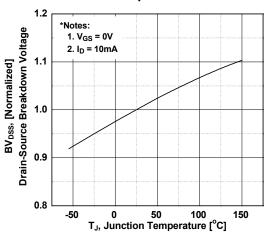


Figure 9. Maximum Safe Operating Area

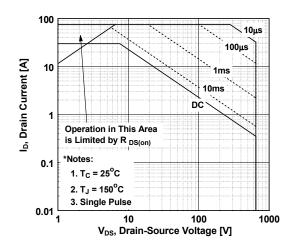
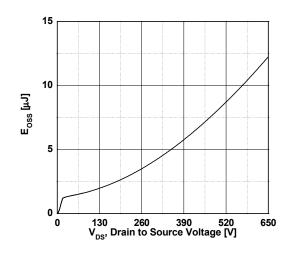
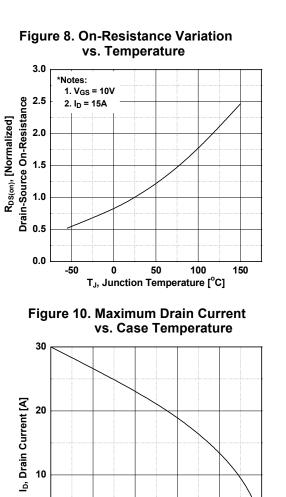
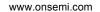


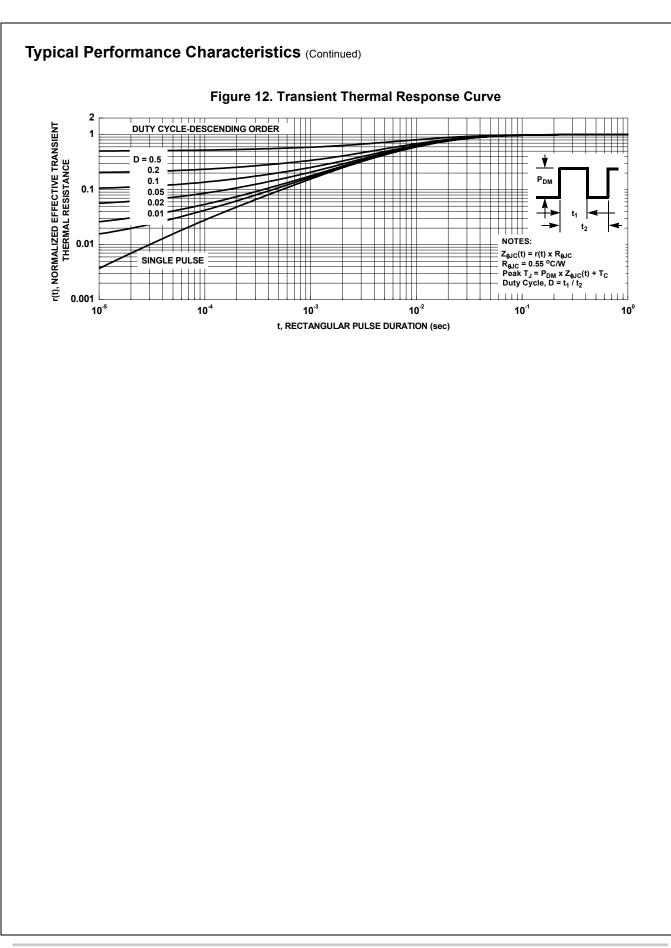
Figure 11. Eoss vs. Drain to Source Voltage

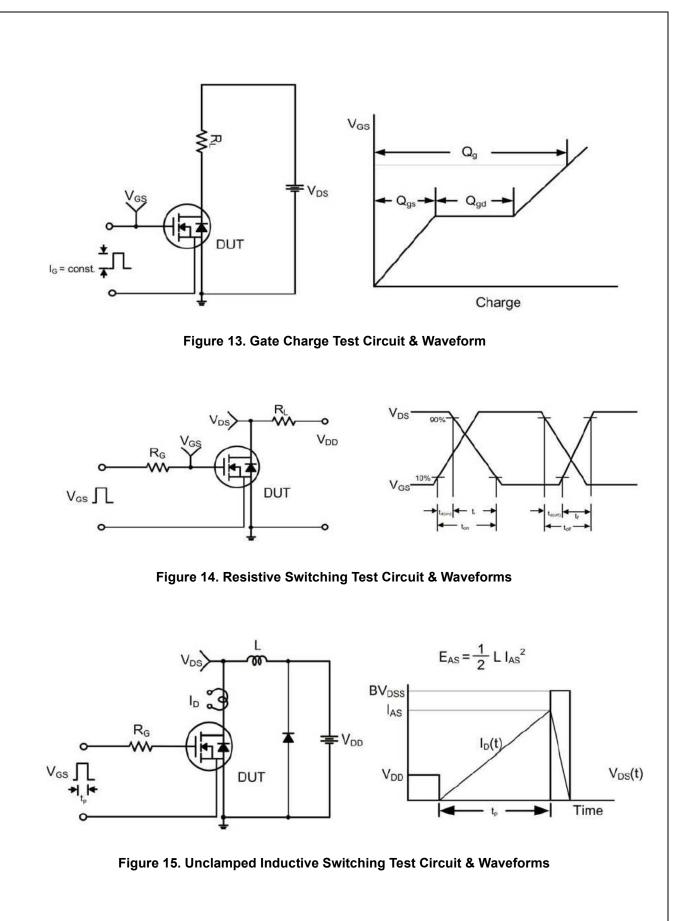


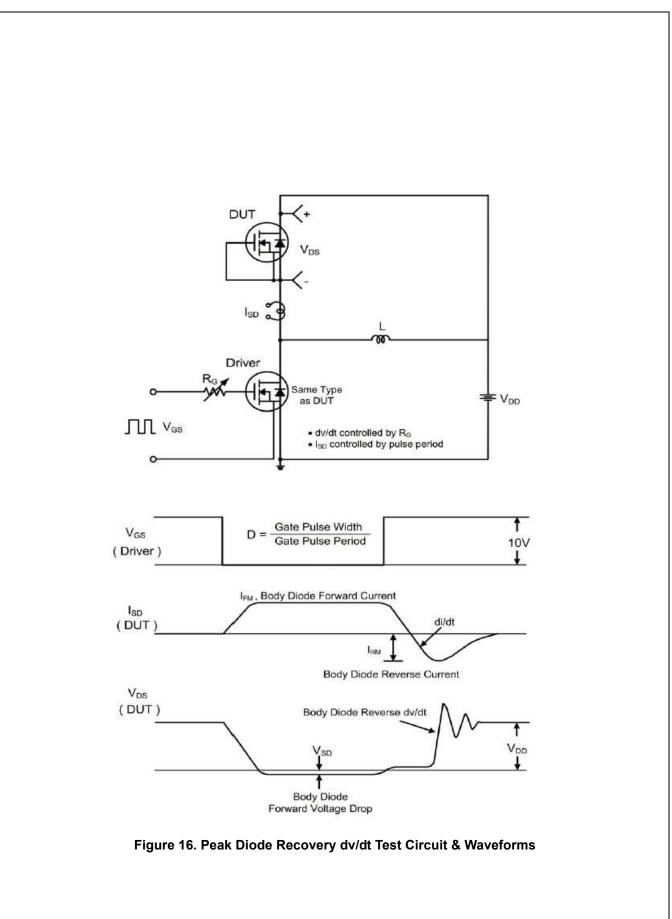


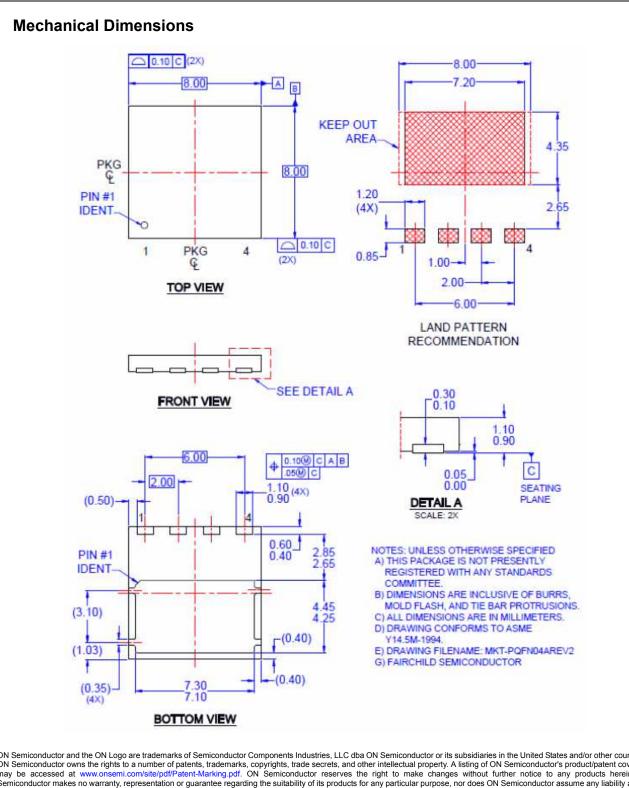


T_c, Case Temperature [°C]









FCMT099N65S3 — N-Channel SuperFET[®] III MOSFET

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